NSN 5961-01-114-1350

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-114-1350 **Inclosure Material:** Metal **Overall Length:** Between 0.628 inches and 0.658 inches **Overall Height:** Between 0.120 inches and 0.150 inches Overall Width: Between 0.490 inches and 0.520 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 12.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6353 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** Demilitarization:

No

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